

FDW2504P

Dual P-Channel 2.5V Specified PowerTrench® MOSFET

General Description

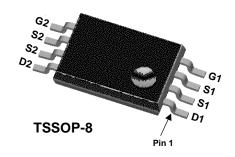
This P-Channel 2.5V specified MOSFET is a rugged gate version of Fairchild Semiconductor's advanced PowerTrench process. It has been optimized for power management applications with a wide range of gate drive voltage (2.5V-12V).

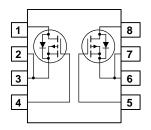
Applications

- Load switch
- Motor drive
- DC/DC conversion
- Power management

Features

- -3.8 A, -20 V, $R_{DS(ON)} = 0.043 \ \Omega \ @V_{GS} = -4.5 \ V$ $R_{DS(ON)} = 0.070 \ \Omega \ @V_{GS} = -2.5 \ V$
- Extended V_{GSS} range (±12V) for battery applications
- · Low gate charge
- High performance trench technology for extremely low $R_{\mbox{\scriptsize DS(ON)}}$
- Low profile TSSOP-8 package





Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{DSS}	Drain-Source Voltage	-20	V
V _{GSS}	Gate-Source Voltage	±12	V
I _D	Drain Current - Continuous (Note	-3.8	A
	- Pulsed	-30	
P _D	Power Dissipation (Note	1a) 1.0	W
	(Note	1b) 0.6	
T_J , T_{STG}	Operating and Storage Junction Temperature Ran	ge —55 to +150	°C

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	125	°C/W
		(Note 1b)	208	

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
2504P	FDW2504P	13"	12mm	2500 units

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics			ı	ı	I.
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	-20			V
$\frac{\Delta BV_{DSS}}{\Delta T_{,J}}$	Breakdown Voltage Temperature Coefficient	$I_D = -250 \mu\text{A}$, Referenced to 25°C		-16		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}$			-1	μΑ
I _{GSSF}	Gate-Body Leakage, Forward	$V_{GS} = -12 \text{ V}, V_{DS} = 0 \text{ V}$			-100	nA
I _{GSSR}	Gate-Body Leakage, Reverse	$V_{GS} = 12 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			100	nA
On Char	acteristics (Note 2)					
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu\text{A}$	-0.6	-1.0	-1.5	V
$\Delta V_{GS(th)} \over \Delta T_J$	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \mu\text{A}$, Referenced to 25°C		3		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	$V_{GS} = -4.5 \text{ V}, I_D = -3.8 \text{ A}$ $V_{GS} = -2.5 \text{ V}, I_D = -3.0 \text{ A}$ $V_{GS} = -4.5 \text{ V}, I_D = -3.8 \text{ A}, T_J = 125 ^{\circ}\text{C}$		0.036 0.056 0.049	0.043 0.070 0.069	Ω
I _{D(on)}	On–State Drain Current	$V_{GS} = -4.5 \text{ V}, I_D = -3.8 \text{ A}, T_J=125^{\circ}\text{C}$ $V_{GS} = -4.5 \text{ V}, V_{DS} = -5 \text{ V}$	-15			Α
g _{FS}	Forward Transconductance	$V_{DS} = -5 \text{ V}, \qquad I_{D} = -3.8 \text{ A}$		13.2		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance	.,, ., .,		1030		pF
C _{oss}	Output Capacitance	$V_{DS} = -10 \text{ V}, \qquad V_{GS} = 0 \text{ V},$		280		pF
C _{rss}	Reverse Transfer Capacitance	f = 1.0 MHz		120		pF
Switchir	ng Characteristics (Note 2)			•	•	
t _{d(on)}	Turn-On Delay Time	$V_{DD} = -5 \text{ V}, \qquad I_{D} = -1 \text{ A},$		11	20	ns
t _r	Turn-On Rise Time	$V_{GS} = -4.5 \text{ V}, \qquad R_{GEN} = 6 \Omega$		18	32	ns
t _{d(off)}	Turn-Off Delay Time			34	55	ns
t _f	Turn-Off Fall Time			34	55	ns
Qg	Total Gate Charge	$V_{DS} = -5 \text{ V}, \qquad I_{D} = -3.8 \text{ A},$		9.7	16	nC
Q _{gs}	Gate-Source Charge	$V_{GS} = -4.5 \text{ V}$		2.2		nC
Q _{gd}	Gate-Drain Charge			2.4		nC
Drain-S	ource Diode Characteristics	and Maximum Ratings		•		•
Is	Maximum Continuous Drain-Sourc				-0.83	Α
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_S = -0.83 \text{ A (Note 2)}$		-0.7	-1.2	V

Notes

^{1.} $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.

a) $\rm \ R_{\theta JA}$ is 125 °C/W (steady state) when mounted on 1 inch² copper pad on FR-4.

b) $\rm \ R_{\theta JA}$ is 208 °C/W (steady state) when mounted on minimum copper pad on FR-4.

^{2.} Pulse Test: Pulse Width < 300µs, Duty Cycle < 2.0.

Typical Characteristics

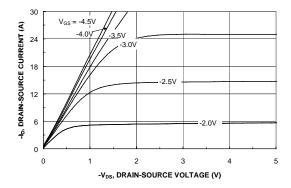


Figure 1. On-Region Characteristics.

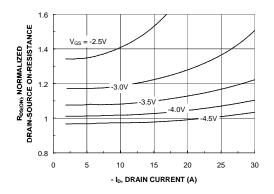


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage.

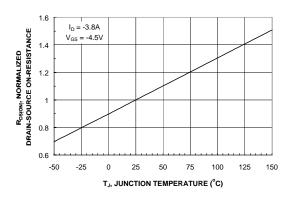


Figure 3. On-Resistance Variation with Temperature.

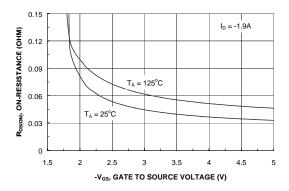


Figure 4. On-Resistance Variation with Gate-to-Source Voltage.

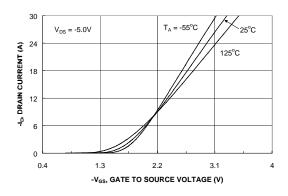


Figure 5. Transfer Characteristics.

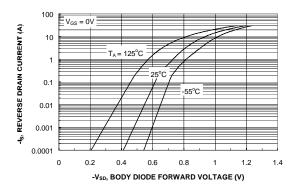
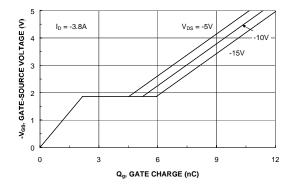


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature.

Typical Characteristics



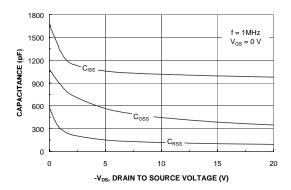
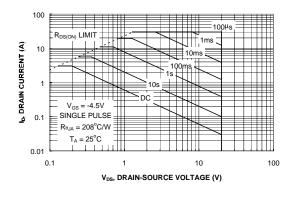


Figure 7. Gate Charge Characteristics.





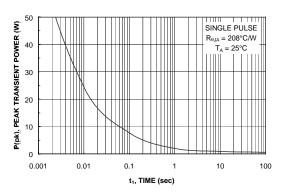


Figure 9. Maximum Safe Operating Area.

Figure 10. Single Pulse Maximum Power Dissipation.

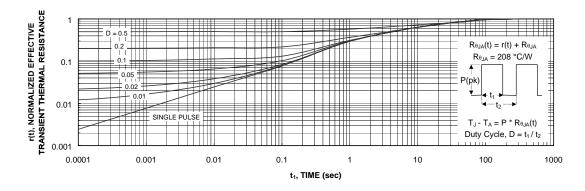


Figure 11. Transient Thermal Response Curve.

Thermal characterization performed using the conditions described in Note 1b. Transient thermal response will change depending on the circuit board design.





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